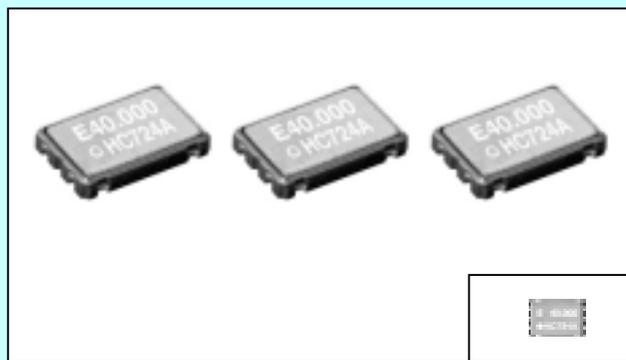


HIGH-FREQUENCY CRYSTAL OSCILLATOR

# SG-710 series

Product number (please contact us)  
**Q33710xxxxxx00**

- Frequency range : 1.8 MHz to 125 MHz
- Operating voltage : 3.3 V or 5.0 V
- Function : Output enable (OE) PTK,PHK  
Standby (/ST) ECK
- Thickness : 1.3 mm Typ.
- Lead(Pb)-free : Comply with EU RoHS directive  
(Lead free completely)



Actual size

## Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		PTK	PHK	ECK	
Output frequency range	f <sub>0</sub>	1.8 MHz to 50 MHz	1.8 MHz to 80 MHz	1.8 MHz to 125 MHz	
Operating voltage	V <sub>DD</sub>	5.0 V ±0.5 V			3.3 V ±0.3 V
Temperature range	Storage temperature	-55 °C to +125 °C			Stored as bare product after unpacking
	Operating temperature	-10 °C to +70 °C, -40 °C to +85 °C			
Frequency stability	Δf/f <sub>0</sub>	B: ±50 × 10 <sup>-6</sup> , C: ±100 × 10 <sup>-6</sup> M: ±100 × 10 <sup>-6</sup>			-10 °C to +70 °C -40 °C to +85 °C
Current consumption	I <sub>OP</sub>	13 mA Max.	15 mA Max.	8 mA Max.	F <sub>0</sub> ≤ 25 MHz, No load condition. (ECK:F <sub>0</sub> ≤ 32 MHz)
		24 mA Max.	26 mA Max.	15 mA Max.	F <sub>0</sub> ≤ 50 MHz, No load condition
		—	34 mA Max.	18 mA Max.	F <sub>0</sub> ≤ 67 MHz, No load condition
		—	40 mA Max.	22 mA Max.	F <sub>0</sub> ≤ 80 MHz, No load condition
		—	—	30 mA Max.	F <sub>0</sub> ≤ 125 MHz, No load condition
Output disable current	I <sub>OE</sub>	6 mA Max.	5 mA Max.	—	F <sub>0</sub> ≤ 25 MHz, OE=GND (PTK, PHK)
		12 mA Max.	10 mA Max.	—	F <sub>0</sub> ≤ 50 MHz, OE=GND (PTK, PHK)
		—	13 mA Max.	—	F <sub>0</sub> ≤ 67 MHz, OE=GND (PTK, PHK)
		—	16 mA Max.	—	F <sub>0</sub> ≤ 80 MHz, OE=GND (PTK, PHK)
Standby current	I <sub>ST</sub>	—	—	15 μA Max.	/ST=GND(ECK)
Duty	tw/t	—	45 % to 55 %	45 % to 55 %	1.8 to 50 MHz, CL=15 pF(ECK)
		45 % to 55 %	—	40 % to 60 %	50 to 125 MHz, CL=15 pF(ECK)
High output voltage	V <sub>OH</sub>	2.4 V Min.	V <sub>DD</sub> -0.5 V Min.	90 % V <sub>DD</sub> Min.	I <sub>OH</sub> =-16 mA(PTK/PHK), -2 mA(ECK)
Low output voltage	V <sub>OL</sub>	0.4 V Max.	0.5 V Max.	10 % V <sub>DD</sub> Max.	I <sub>OL</sub> = 16 mA(PTK/PHK), 2 mA(ECK)
Output loadcondition(TTL)	N	10 TTL Max.	10 TTL Max.	—	
Output loadcondition(CMOS)	C <sub>L</sub>	15 pF Max.	50 pF Max.	15 pF Max.	
Output enable / disable input voltage	V <sub>IH</sub>	2.0 V Min.	2.0 V Min.	70 % V <sub>DD</sub> Min.	OE terminal (PTK, PHK)
	V <sub>IL</sub>	0.8 V Max.	0.8 V Max.	30 % V <sub>DD</sub> Max.	/ST terminal (ECK)
Output rise fall time	t <sub>r</sub> t <sub>f</sub>	—	5 ns Max.	6 ns Max.	CMOS load: 10 % V <sub>DD</sub> to 90 % V <sub>DD</sub> level
		5 ns Max.	—	—	TTL load: 0.4 V to 2.4 V level
Oscillation start up time	t <sub>OSC</sub>	10 ms Max.			Time at minimum operating voltage to be 0 s
Aging	f <sub>a</sub>	±5 × 10 <sup>-6</sup> / year Max.			T <sub>a</sub> =+25 °C, V <sub>DD</sub> =5.0 V / 3.3 V, First year.

## External dimensions

(Unit:mm) ■ Recommended soldering pattern (Unit:mm)

